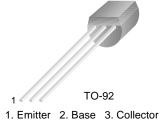


KSP2222A

General Purpose Transistor

- Collector-Emitter Voltage: V_{CEO}= 40V
 Collector Power Dissipation: P_C (max)=625mW
- Refer KSP2222 for graphs



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

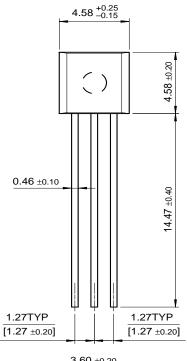
Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	75	V
V _{CEO}	Collector-Emitter Voltage	40	V
V _{EBO}	Emitter-Base Voltage	6	V
I _C	Collector Current	600	mA
P _C	Collector Power Dissipation	625	mW
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

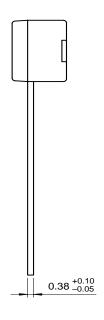
Electrical Characteristics T_a =25°C unless otherwise noted

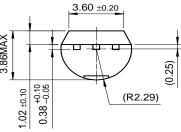
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_{C}=10\mu A, I_{E}=0$	75			V
BV _{CEO}	Collector Emitter Breakdown Voltage	I _C =10mA, I _B =0	40			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =10μA, I _C =0	6			V
I _{CBO}	Collector Cut-off Current	V _{CB} =60V, I _E =0			0.01	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB}=3V$, $I_{C}=0$			10	nA
h _{FE}	DC Current Gain	$\begin{array}{c} I_{C}{=}0.1\text{mA},\ V_{CE}{=}10\text{V} \\ V_{CE}{=}10\text{V},\ I_{C}{=}1\text{mA} \\ V_{CE}{=}10\text{V},\ I_{C}{=}10\text{mA} \\ V_{CE}{=}10\text{V},\ ^{*}I_{C}{=}15\text{omA} \\ V_{CE}{=}10\text{V},\ ^{*}I_{C}{=}50\text{omA} \end{array}$	35 50 75 100 40		300	
V _{CE} (sat)	* Collector-Emitter Saturation Voltage	I _C =150mA, I _B =15mA I _C =500mA, I _B =50mA			0.3 1	V V
V _{BE} (sat)	* Base-Emitter Saturation Voltage	I _C =150mA, I _B =15mA I _C =500mA, I _B =50mA		0.6	1.2 2	V V
f _T	Current Gain Bandwidth Product	V _{CE} =20V, I _C =20mA f=100MHz	300			MHz
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0, f=1MHz			8	pF
t _{ON}	Turn On Time	V _{CC} =30V, I _C =150mA I _{B1} =15mA, V _{BE} (off)=0.5V			35	ns
t _{OFF}	Turn Off Time	V _{CC} =30V, I _C =150mA I _{B1} =I _{B2} =15mA			285	ns
NF	Noise Figure	I _C =100μA, V _{CE} =10V R _S =IKΩ, f=1KHz			4	dB

^{*} Pulse Test: Pulse Width≤300μs, Duty Cycle≤2%
* Also available as and PN2222A

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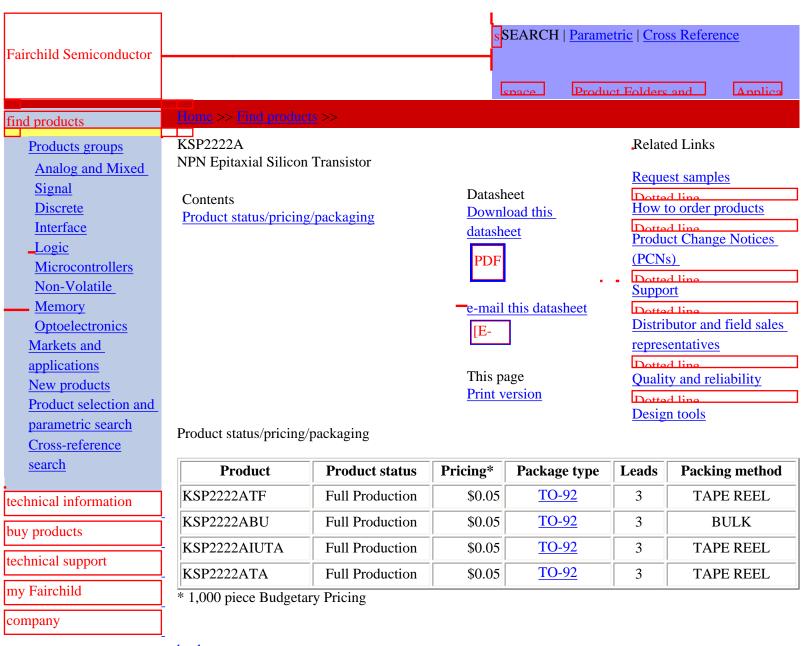
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